

TECHNICAL DATA DATA SHEET 1190, REV. A

HERMETIC POWER SCHOTTKY RECTIFIER

DESCRIPTION: A 60-VOLT, 30 AMP, POWER SCHOTTKY RECTIFIER IN A CERAMIC HERMETIC LCC-5 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

RATING RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	60	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_{\rm C}$ =77 $^{\rm O}$ C, 50% duty cycle)	Io	30	Amps
MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine) per leg	I _{FSM}	120	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V) per leg (TYP)	C _T	400	pF
MAXIMUM THERMAL RESISTANCE, Junction to Case (PER PACKAGE) MAXIMUM OPERATING TEMPERATURE RANGE		1.75	°C/W
		-55 to + 150	°C
MAXIMUM STORAGE TEMPERATURE RANGE	Tstg	-55 to + 150	°C

ELECTRICAL CHARACTERISTICS

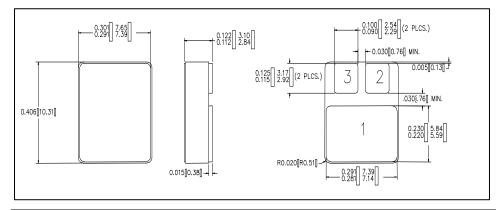
CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 15 Amps) (PER LEG)			
T _J = 25 °C	V_{f}	1.00	Volts
T _J = 125 °C	- 1	0.88	
MAXIMUM REVERSE CURRENT (I _r @ 30V PIV) (PER LEG)			
T _J = 25 °C	I _r	0.2	mA
T _J = 125 °C		15	

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MECHANICAL DIMENSIONS: IN Inches / mm



2 1 3

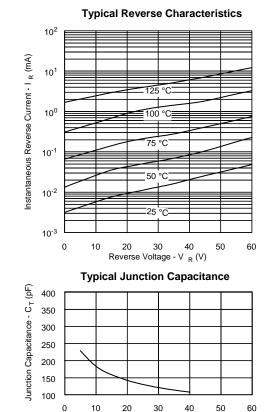


LCC-5

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER, COMMON CATHODE (P)	CATHODE	ANODE	ANODE

Typical Forward Characteristics 10¹ 10² 10⁻² 10⁻² 10⁻² 0.0 0.2 0.4 Forward Voltage Drop - V F (V)



Reverse Voltage - V _R (V)



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